TECHNICAL DATA DATA SHEET 4704, REV. -

# HERMETIC POWER SCHOTTKY RECTIFIER Very Low Forward Voltage

# **Applications:**

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

#### Features:

- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics

# **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	15	V
Max. Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle, rectangular wave form (Single/Doubler)	45	Α
Max. Peak One Cycle Non- Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine wave (per leg)	200	Α
Max. Thermal Resistance	$R_{\theta JC}$	(Common Cathode/Common Anode/Doubler) (per leg)	0.33	°C/W
Max. Junction Temperature	TJ	-	-65 to +100	°C
Max. Storage Temperature	T <sub>stg</sub>	-	-65 to +100	°C

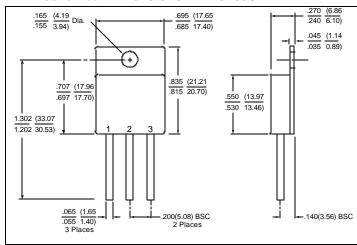
# **Electrical Characteristics:**

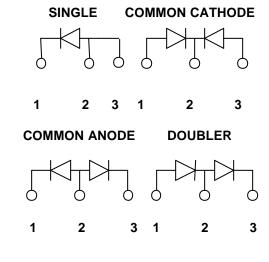
Characteristics	<b>Symbol</b>	Condition	Max.	Units
Max. Forward Voltage Drop	$V_{F1}$	@ 45A, Pulse, T <sub>J</sub> = 25 °C	0.57	V
		(per leg)		
	$V_{F2}$	@ 45A, Pulse, T <sub>J</sub> = 75 °C	0.53	V
		(per leg)		
Max. Reverse Current	$I_{R1}$	@V <sub>R</sub> = 15V, Pulse,	40	mA
		T <sub>J</sub> = 25 °C (per leg)		
	I <sub>R2</sub>	@V <sub>R</sub> = 15V, Pulse,	2000	mA
		T <sub>J</sub> = 100 °C (per leg)		
Max. Junction Capacitance	$C_T$	$@V_R = 5V, T_C = 25  ^{\circ}C$	7200	pF
		$f_{SIG} = 1MHz,$		
		$V_{SIG} = 50 \text{mV (p-p) (per leg)}$		

#### **SENSITRON**

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### Mechanical Dimensions: In Inches / mm





# **TO-258**

### **PINOUT TABLE**

TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
DUAL RECTIFIER, COMMON CATHODE (P)	ANODE 1	COMMON CATHODE	ANODE 2
DUAL RECTIFIER, COMMON ANODE (N)	CATHODE 1	COMMON ANODE	CATHODE 2
DUAL RECTIFIER, DOUBLER (D)	ANODE	CATHODE/ANODE	CATHODE



#### **TECHNICAL DATA**

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